

Features

- · Trench MV MOSFET Technology
- · Voltage Controlled Small Signal Switch
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-Channel MOSFET

Maximum Ratings

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 357°C/W Junction to Ambient^(Note 2)

Thermal Resistance. 601 6,77 Garietien to 7 this ion.					
Parameter	Symbol	Rating	Unit		
Drain-Source Voltage		V _{DS}	100	٧	
Gate-Source Voltage		V_{GS}	±20	V	
Drain Current-Continuous	T _A =25°C	I _D	0.17	- A	
	T _A =100°C		0.11		
Drain Current-Pulsed ^(Note3)		I _{DM}	0.68	Α	
Power Dissipation ^(Note4)		P _D	0.35	W	

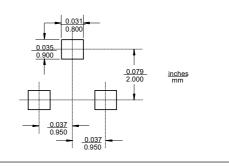
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2.The value of R0JA is measured with the device mounted on the minimum recommend pad size, in the still air environment with TA =25 $^\circ$ C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

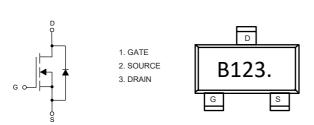
SOT-23

DIMENSIONS					
DIM INC		HES	MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.110	0.120	2.80	3.04	
В	0.083	0.104	2.10	2.64	
С	0.047	0.055	1.20	1.40	
D	0.034	0.041	0.85	1.05	
Е	0.067	0.083	1.70	2.10	
F	0.018	0.024	0.45	0.60	
G	0.0004	0.006	0.01	0.15	
Н	0.035	0.043	0.90	1.10	
J	0.003	0.007	0.08	0.18	
K	0.012	0.020	0.30	0.51	
L	0.007	0.020	0.20	0.50	

Suggested Solder Pad Layout



Internal Structure and Marking Code





ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V	
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.0	1.Ï	2.8	V	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =± 20V, V _{DS} =0V			±50	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA	
		V _{DS} =20V, V _{GS} =0V			10	nA	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =0.17A		ŒĬ	6	Ω	
	26(611)	V _{GS} =4.5V, I _D =0.17A		ŒÏ	10		
Forward Transconductance	9 FS	V_{DS} =5V, I_{D} =0.17A		450		mS	
Gate Resistance	R_g	f=1 MHz, Open drain		6.0		Ω	
Diode Characteristics	•		,	•			
Continuous Body Diode Current	Is				0.17	Α	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =0.34A			1.3	V	
Reverse Recovery Time	t _{rr}	1 - 1 0 - 11 / 44-1000 / 100		20		ns	
Reverse Recovery Charge	Q _{rr}	I _F =1A, dI _F /dt=100A/μs		6.0		nC	
Dynamic Characteristics			,				
Input Capacitance	C _{iss}			35			
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V,f=1MHz		2.5		pF	
Reverse Transfer Capacitance	C _{rss}			1.6			
Total Gate Charge	Q _g			1.6			
Gate-Source Charge	Q_{gs}	V _{DS} =50V,V _{GS} =10V,I _D =0.2A		0.5		nC	
Gate-Drain Charge	Q_{gd}			0.4			
Turn-On Delay Time	t _{d(on)}			4			
Turn-On Rise Time	t _r	V _{DD} =50V, V _{GS} =10V,		20			
Turn-Off Delay Time	t _{d(off)}	$R_{GEN}=3\Omega$, $I_{DS}=1A$		7		ns	
Turn-Off Fall Time	t _f			31			



Curve Characteristics

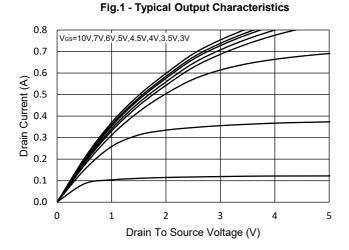


Fig.2 - Transfer Characteristic

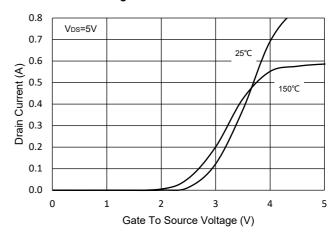


Fig. 3 - $R_{DS(ON)}$ — V_{GS}

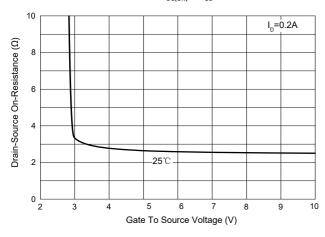


Fig.4 - $R_{DS(ON)}$ - I_D

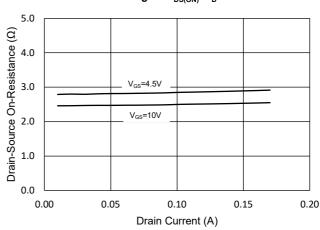


Fig. 5 - Capacitance Characteristics

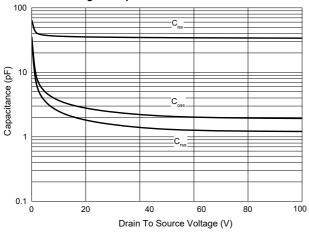
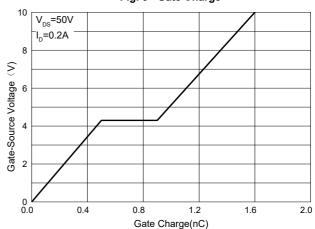
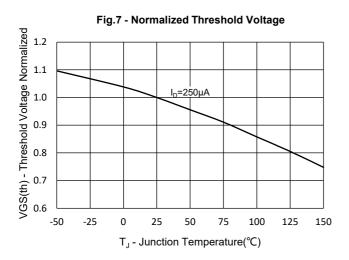


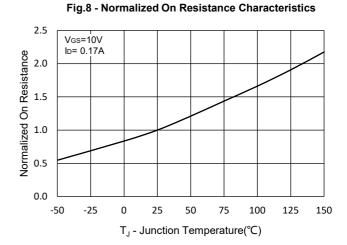
Fig. 6 - Gate Charge

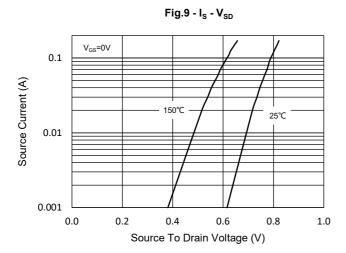


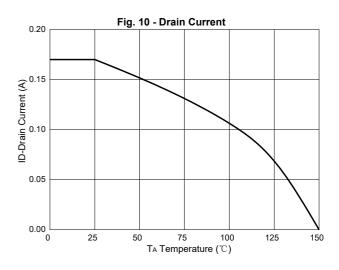


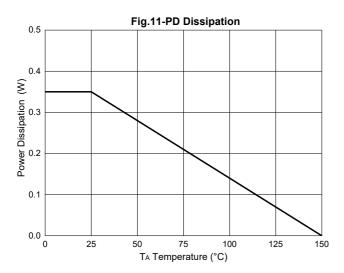
Curve Characteristics













Curve Characteristics

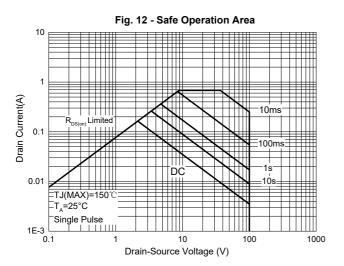
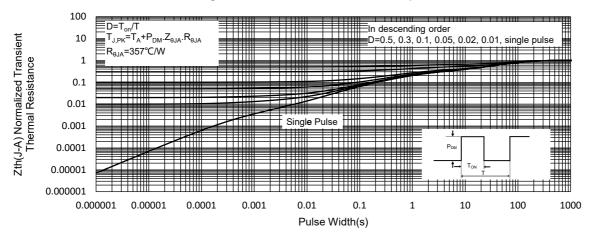


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Device Packing	
Part Number-TP	Tape&Reel: 3Kpcs/Reel	
Part Number-13P	Tape&Reel: 10Kpcs/Reel	

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